## NSN 5961-00-929-3757

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-929-3757 **Inclosure Material:** Glass and metal **Overall Length:** Between 1.019 inches and 1.050 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.432 inches and 0.445 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 250.0 reverse voltage, peak **Current Rating Per Characteristic:** 3.30 amperes forward current, average absolute **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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